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				Application Number	10/660,565-Conf. #5308
				Filing Date	September 12, 2003
				First Named Inventor	Jeff A. McKee
				Art Unit	2811
				Examiner Name	Andrew O. Arena
Sheet	1	of	1	Attorney Docket Number	M4065.0570/P570-A

U.S. PATENT DOCUMENTS					
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/A.O.A./	CA	H. Watanabe et al., "Hemispherical Grained Si Formation on <i>in-situ</i> Phosphorus Doped Amorphous-Si Electrode for 256Mb DRAM's Capacitor", IEEE Transactions on Electron Devices, Vol. 42, No. 7, July 1995.			

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Examiner Signature	/Andrew O. Arena/	Date Considered	02/18/2009
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